BYV74 series

GENERAL DESCRIPTION

Glass passivated, high efficiency rectifier diodes in a plastic envelope featuring low forward voltage drop, ultra fast reverse recovery times and soft recovery characteristic. They are intended for use in switched mode power supplies and high frequency circuits in general, where both low conduction losses and low switching losses are essential.

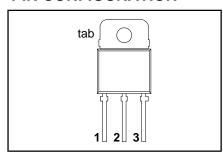
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BYV74-	300	400	500	
V_{RRM}	Repetitive peak reverse voltage	300	400	500	V
V_{F}	Forward voltage	1.12	1.12	1.12	V
I _{O(AV)}	Average output current (both diodes conducting)	30	30	30	Α
t _{rr}	Reverse recovery time	60	60	60	ns

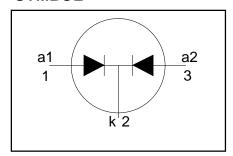
PINNING - SOT93

PIN	DESCRIPTION	
1	Anode 1 (a)	
2	Cathode (k)	
3	Anode 2 (a)	
tab	Cathode (k)	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT	
V _{RRM} V _{RWM} V _R	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage	T _{mb} ≤ 136°C		-300 300 300 300	-400 400 400 400	-500 500 500 500	V V
I _{O(AV)}	Average output current (both diodes conducting) ¹	square wave; δ = 0.5; $T_{mb} \le 94$ °C sinusoidal; a = 1.57; $T_{mb} \le 98$ °C	-		30 27		A A
I _{O(RMS)}	RMS output current (both diodes conducting)		-		43		Α
I _{FRM}	Repetitive peak forward current per diode	$t = 25 \mu s; \delta = 0.5;$ $T_{mb} \le 94 ^{\circ}C$	-		30		Α
I _{FSM}	Non-repetitive peak forward current per diode.	t = 10 ms t = 8.3 ms sinusoidal; with reapplied V_RRM(max)	-		150 160		A A
I ² t T _{stg} T _j	I ² t for fusing Storage temperature Operating junction temperature	t = 10 ms	- -40 -		112 150 150		A²s °C °C

August 1996 1 Rev 1.200

¹ Neglecting switching and reverse current losses.

For output currents in excess of 20 A, connection should be made to the exposed metal mounting base.

BYV74 series

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{\text{th } j\text{-hs}}$ $R_{\text{th } j\text{-a}}$	heatsink	per diode both diodes conducting in free air.	1 1 1	- - 45	2.4 1.4 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

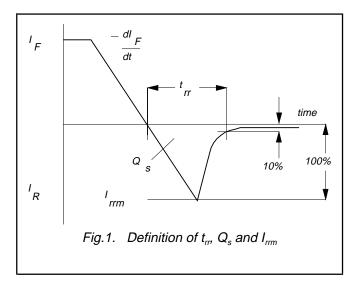
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{F}	Forward voltage (per diode)	$I_F = 15 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.95	1.12	V
	- "	I _F = 15 A	-	1.08	1.25	V
		$I_{\rm F} = 30 \text{ A}$	-	1.15	1.36	V
I _R	Reverse current (per diode)	$V_R = V_{RRM}$	-	10	50	μΑ
		$V_{R} = V_{RRM}^{(i)}; T_{j} = 100 ^{\circ}C$	-	0.3	0.8	mΑ

DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q_s	Reverse recovery charge (per diode)	$I_F = 2 \text{ A to } V_R \ge 30 \text{ V};$ $dI_F/dt = 20 \text{ A/}\mu\text{s}$	-	40	60	nC
t _{rr}	Reverse recovery time (per diode)	$I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$	-	50	60	ns
I _{rrm}	Peak reverse recovery current (per diode)	$I_F = 10 \text{ A to } V_R \ge 30 \text{ V};$ $dI_F/dt = 50 \text{ A/}\mu\text{s}; T_i = 100^{\circ}\text{C}$	-	4.2	5.2	Α
V_{fr}	Forward récovery voltage (per diode)	$I_{\rm F} = 10 \text{ A}; dI_{\rm F}/dt = 10 \text{ A/}\mu\text{s}$	-	2.5	1	V

BYV74 series



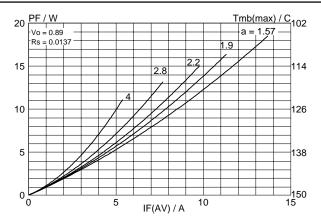
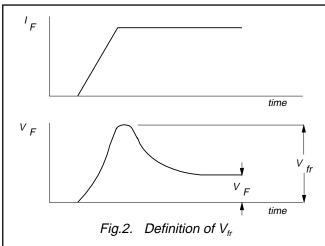
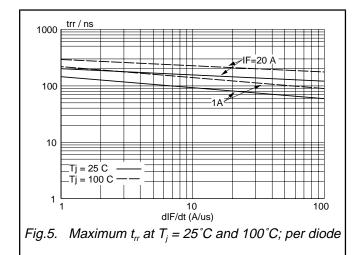
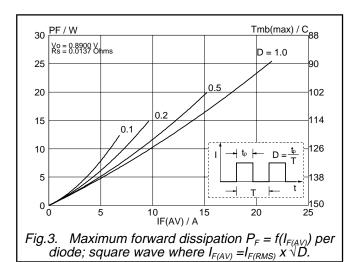
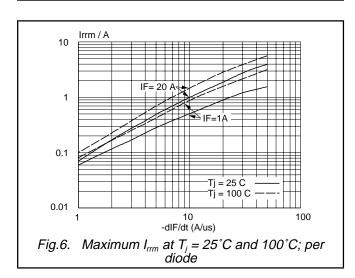


Fig.4. Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; sinusoidal current waveform where a = f form factor $= I_{F(RMS)} / I_{F(AV)}$.









BYV74 series

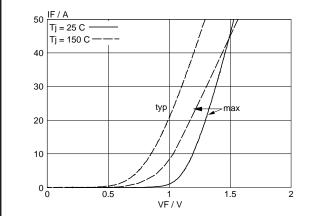


Fig.7. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

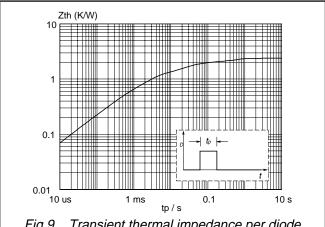


Fig.9. Transient thermal impedance per diode $Z_{th j-mb} = f(t_p)$

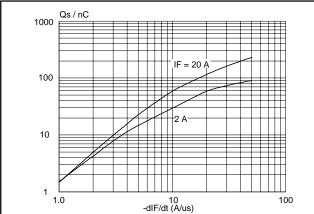
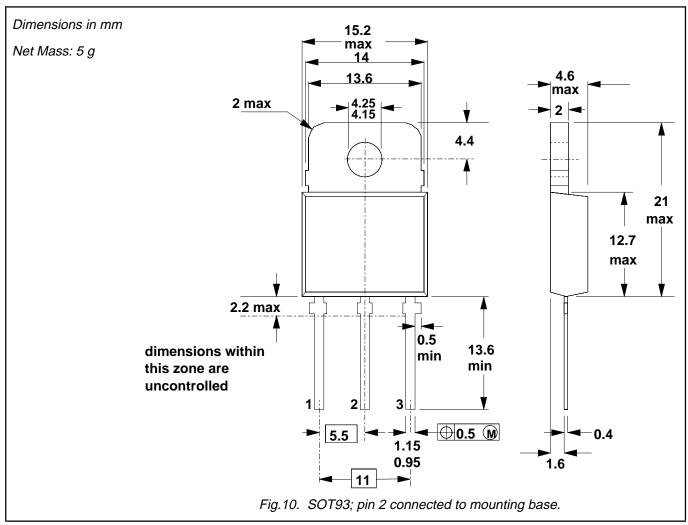


Fig.8. Maximum Q_s at $T_i = 25^{\circ}C$; per diode

BYV74 series

MECHANICAL DATA



- Refer to mounting instructions for SOT93 envelope.
 Epoxy meets UL94 V0 at 1/8".

BYV74 series

DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limitin or conferen					

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

© Philips Electronics N.V. 1996

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.